

Amendments to the Specification:

Please amend the specification by inserting the paragraph below, after the title on page 1.

Cross-Reference to Related Application

[0001.1] This application claims priority based on International Patent Application No. PCT/FR2003/050045, entitled "Quasi-Vertical Power Semiconductor Device on a Composite Substrate" by Francois TEMPLIER, Lea DI CIOCCIO, Thierry BILLON and Fabrice LETERTRE, which claims priority of French Application No. 02/10883, filed on September 3, 2002, and which was not published in English.